

TXU0202 具有施密特触发输入和三态输出的双位定向电压电平转换器

1 特性

- 完全可配置的双电源轨设计可允许各个端口在 1.1V 至 5.5V 范围内运行
- 在 3.3V 至 5.0V 范围内，支持高达 200Mbps 的速率
- 施密特触发输入可实现慢速和高噪声输入
- 带集成静态下拉电阻器的输入阻止通道流动
- 高驱动强度（在 5V 时最高达 12mA）
- 低功耗
 - 最大值 2.5μA (25°C)
 - 最大值 6μA (–40°C 至 125°C)
- V_{CC} 隔离和 V_{CC} 断开 ($I_{off-float}$) 特性
 - 如果任何一个 V_{CC} 输入低于 100mV 或已断开，则所有输出均禁用且处于高阻抗状态
- I_{off} 支持局部断电模式运行
- 带有 $V_{CC(MIN)}$ 电路的控制逻辑 (OE) 允许从端口 A 或 B 进行控制
- 引脚排列兼容 TXB 系列电平转换器
- 可用于支持常见应用的另一型号：TXU0102
- 工作温度范围为 –40°C 至 +125°C
- 闩锁性能超过 100mA，符合 JESD 78 II 类规范
- ESD 保护性能超过 JESD 22 规范要求
 - 2500V 人体放电模型
 - 1500V 充电器件模型

2 应用

- 消除缓慢或嘈杂输入信号
- 驱动指示 LED 或蜂鸣器
- 机械开关去抖
- 通用 I/O 电平转换
- 推挽电平转换 (UART、SPI、JTAG 等等)

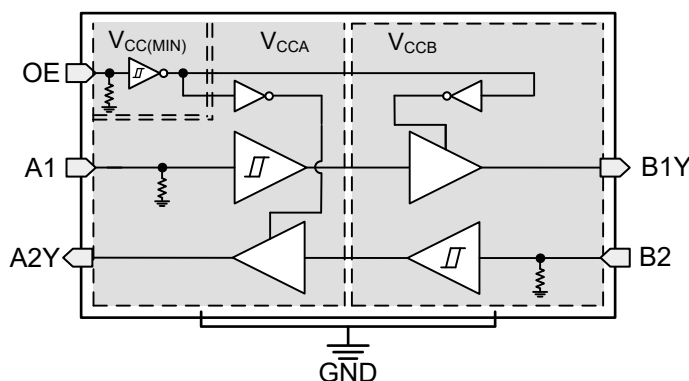
3 说明

TXU0202 是一款 2 位双电源同相定向电压电平转换器件。Ax 引脚以 V_{CCA} 逻辑电平为基准，OE 引脚可以 V_{CCA} 或 V_{CCB} 逻辑电平为基准，Bx 引脚以 V_{CCB} 逻辑电平为基准。A 端口能够接受 1.1V 至 5.5V 的输入电压，而 B 端口也可接受 1.1V 至 5.5V 的输入电压。如果 OE 相对于任一电源设为高电平，可能会发生从 A 到 B 或从 B 到 A 的定向数据传输。OE 设为低电平时，所有输出引脚均处于高阻抗状态。请参阅 [器件功能模式](#)，简要了解控制逻辑的运行。

器件信息(1)

器件型号	封装	封装尺寸 (标称值)
TXU0202	VSSOP (DCU) (8)	2.30mm × 2.00mm
	SON (DTT) (8)	1.95 mm × 1.00 mm
	X2SON (DTM) (8)	1.35mm × 0.80mm

(1) 如需了解所有可用封装，请参阅数据表末尾的可订购产品附录。



TXU0202 功能方框图

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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision * (November 2021) to Revision A (March 2022)

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5 Related Products

[TXU0x02 2-Bit
Unidirectional
Voltage-Level
Translators](#)

[TXU0102](#)

TXU0x02 are 2-bit, dual-supply noninverting fixed direction voltage level translators. These devices are compatible with the TXB0102 because of the same pinout, which allows for a drop in replacement. The OE pin can be referenced to either V_{CCA} or V_{CCB} logic levels allowing for one of the TXU0x02 devices to be used for fixed direction, high drive applications which the TXB0102 is not recommended to support.

TXU0102 is a 2-bit, dual-supply noninverting fixed direction voltage level translators with both channels in the same direction commonly used for GPIO translation.

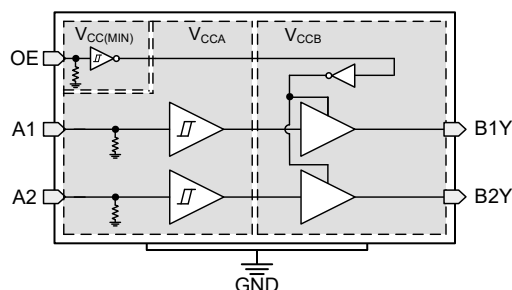


图 5-1. TXU0102 Functional Block Diagram

6 Pin Configuration and Functions—TXU0202

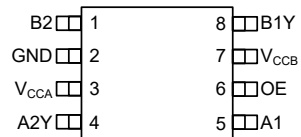


图 6-1. DCU Package, 8-Pin VSSOP (Top View)

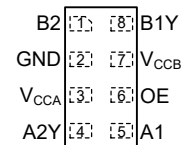


图 6-2. DTT Package, 8-Pin SON Transparent (Top View)

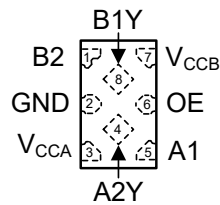


图 6-3. DTM Package, 8-Pin X2SON Transparent (Top View)

表 6-1. TXU0202 Pin Functions

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
B2	1	I	Input B2. Referenced to V_{CCB} .
GND	2	—	Ground.
V_{CCA}	3	—	A-port supply voltage. $1.1\text{ V} \leq V_{CCA} \leq 5.5\text{ V}$
A2Y	4	O	Output A2. Referenced to V_{CCA} .
A1	5	I	Input A1. Referenced to V_{CCA} .
OE	6	I	Output Enable. Pull to GND to place all outputs in high-impedance mode. Pull to V_{CCA} or V_{CCB} to enable all outputs.
V_{CCB}	7	—	B-port supply voltage. $1.1\text{ V} \leq V_{CCB} \leq 5.5\text{ V}$
B1Y	8	O	Output B1. Referenced to V_{CCB} .

(1) I = input, O = output.

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CCA}	Supply voltage A		−0.5	6.5	V
V _{CCB}	Supply voltage B		−0.5	6.5	V
V _I	Input Voltage ⁽²⁾	I/O Ports (A Port)	−0.5	6.5	V
		I/O Ports (B Port)	−0.5	6.5	
		OE	−0.5	6.5	
V _O	Voltage applied to any output in the high-impedance or power-off state ⁽²⁾	A Port	−0.5	6.5	V
		B Port	−0.5	6.5	
V _O	Voltage applied to any output in the high or low state ^{(2) (3)}	A Port	−0.5	V _{CCA} + 0.5	V
		B Port	−0.5	V _{CCB} + 0.5	
I _{IK}	Input clamp current	V _I < 0	−20		mA
I _{OK}	Output clamp current	V _O < 0	−20		mA
I _O	Continuous output current		−25	25	mA
	Continuous current through V _{CC} or GND		−100	100	mA
T _j	Junction Temperature			150	°C
T _{stg}	Storage temperature		−65	150	°C

- (1) Operation outside the [Absolute Maximum Ratings](#) may cause permanent device damage. [Absolute Maximum Ratings](#) do not imply functional operation of the device at these or any other conditions beyond those indicated under [Recommended Operating Conditions](#). If briefly operating outside the [Recommended Operating Conditions](#), but within the [Absolute Maximum Ratings](#), this device may not sustain damage, but it may not be fully functional. Operating the device in this manner may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The output positive-voltage rating may be exceeded up to 6.5 V maximum if the output current rating is observed.

7.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2500	V
		Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 ⁽²⁾	±1500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted) ⁽¹⁾ ⁽²⁾ ⁽³⁾

			MIN	MAX	UNIT
V _{CCA}	Supply voltage A		1.08	5.5	V
V _{CCB}	Supply voltage B		1.08	5.5	V
I _{OH}	High-level output current	V _{CCO} = 1.1 V		–1.5	mA
		V _{CCO} = 1.4 V		–3	
		V _{CCO} = 1.65 V		–4.5	
		V _{CCO} = 2.3 V		–8	
		V _{CCO} = 3 V		–10	
		V _{CCO} = 4.5 V		–12	
I _{OL}	Low-level output current	V _{CCO} = 1.1 V		1.5	mA
		V _{CCO} = 1.4 V		3	
		V _{CCO} = 1.65 V		4.5	
		V _{CCO} = 2.3 V		8	
		V _{CCO} = 3 V		10	
		V _{CCO} = 4.5 V		12	
V _I	Input voltage ⁽³⁾		0	5.5	V
V _O	Output voltage	Active State	0	V _{CCO}	V
		Tri-State	0	5.5	
T _A	Operating free-air temperature		–40	125	°C

(1) V_{CCI} is the V_{CC} associated with the input port.

(2) V_{CCO} is the V_{CC} associated with the output port.

(3) All control inputs and data I/Os of this device have weak pulldowns to ensure the line is not floating when undefined external to the device. The input leakage from these weak pulldowns is defined by the I_I specification indicated under [Electrical Characteristics](#).

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TXU0202			UNIT
		DCU (VSSOP)	DTT (SON)	DTM (X2SON)	
		8 PINS	8 PINS	8 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	257.0	TBD	253.6	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	106.9	TBD	157.5	°C/W
R _{θJB}	Junction-to-board thermal resistance	168.3	TBD	157.8	°C/W
Y _{JT}	Junction-to-top characterization parameter	47.2	TBD	15.6	°C/W
Y _{JB}	Junction-to-board characterization parameter	167.3	TBD	157.6	°C/W
R _{θJC(bottom)}	Junction-to-case (bottom) thermal resistance	N/A	TBD	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

7.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

PARAMETER		TEST CONDITIONS	V _{CCA}	V _{CCB}	Operating free-air temperature (T _A)									UNIT
					25°C			–40°C to 85°C			–40°C to 125°C			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V _{T+}	Positive-going input-threshold voltage	Data Inputs (A _x , B _x) (Referenced to V _{CCI})	1.1 V	1.1 V				0.44	0.88	0.44	0.88			V
			1.4 V	1.4 V				0.60	0.98	0.60	0.98			
			1.65 V	1.65 V				0.76	1.13	0.76	1.13			
			2.3 V	2.3 V				1.08	1.56	1.08	1.56			
			3 V	3 V				1.48	1.92	1.48	1.92			
			4.5 V	4.5 V				2.19	2.74	2.19	2.74			
			5.5 V	5.5 V				2.65	3.33	2.65	3.33			
		OE (Referenced to V _{CCA} or V _{CCB})	1.1 V	1.1 V				0.44	0.88	0.44	0.88			V
			1.4 V	1.4 V				0.60	0.98	0.60	0.98			
			1.65 V	1.65 V				0.76	1.13	0.76	1.13			
			2.3 V	2.3 V				1.08	1.56	1.08	1.56			
			3 V	3 V				1.48	1.92	1.48	1.92			
			4.5 V	4.5 V				2.19	2.74	2.19	2.74			
			5.5 V	5.5 V				2.65	3.33	2.65	3.33			
V _{T–}	Negative-going input-threshold voltage	Data Inputs (A _x , B _x) (Referenced to V _{CCI})	1.1 V	1.1 V				0.17	0.48	0.17	0.48			V
			1.4 V	1.4 V				0.28	0.59	0.28	0.59			
			1.65 V	1.65 V				0.35	0.69	0.35	0.69			
			2.3 V	2.3 V				0.56	0.97	0.56	0.97			
			3 V	3 V				0.89	1.5	0.89	1.5			
			4.5 V	4.5 V				1.51	1.97	1.51	1.97			
			5.5 V	5.5 V				1.88	2.4	1.88	2.4			
		OE (Referenced to V _{CCA} or V _{CCB})	1.1 V	1.1 V				0.17	0.48	0.17	0.48			V
			1.4 V	1.4 V				0.28	0.59	0.28	0.59			
			1.65 V	1.65 V				0.35	0.69	0.35	0.69			
			2.3 V	2.3 V				0.56	0.97	0.56	0.97			
			3 V	3 V				0.89	1.5	0.89	1.5			
			4.5 V	4.5 V				1.51	1.97	1.51	1.97			
			5.5 V	5.5 V				1.88	2.46	1.88	2.46			
ΔV _T	Input-threshold hysteresis (V _{T+} – V _{T–})	Data Inputs (A _x , B _x) (Referenced to V _{CCI})	1.1 V	1.1 V				0.2	0.4	0.2	0.4			V
			1.4 V	1.4 V				0.25	0.5	0.25	0.5			
			1.65 V	1.65 V				0.3	0.55	0.3	0.55			
			2.3 V	2.3 V				0.38	0.65	0.38	0.65			
			3 V	3 V				0.46	0.72	0.46	0.72			
			4.5 V	4.5 V				0.58	0.93	0.58	0.93			
			5.5 V	5.5 V				0.69	1.06	0.69	1.06			
		OE (Referenced to V _{CCA} or V _{CCB})	1.1 V	1.1 V				0.15	0.41	0.15	0.41			V
			1.4 V	1.4 V				0.2	0.5	0.2	0.5			
			1.65 V	1.65 V				0.23	0.55	0.23	0.55			
			2.3 V	2.3 V				0.32	0.65	0.32	0.65			
			3 V	3 V				0.39	0.72	0.39	0.72			
			4.5 V	4.5 V				0.57	0.97	0.57	0.97			
			5.5 V	5.5 V				0.69	1.18	0.69	1.18			

7.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

PARAMETER		TEST CONDITIONS	V _{CCA}	V _{CCB}	Operating free-air temperature (T _A)									UNIT
					25°C			–40°C to 85°C			–40°C to 125°C			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V _{OH}	High-level output voltage ⁽³⁾	I _{OH} = –0.1 mA	1.1V – 5.5V	1.1V – 5.5V				V _{CCO} – 0.1			V _{CCO} – 0.1			V
		I _{OH} = –0.5 mA	1.1 V	1.1 V				0.82			0.82			
		I _{OH} = –3 mA	1.4 V	1.4 V				1			1			
		I _{OH} = –4.5 mA	1.65 V	1.65 V				1.2			1.2			
		I _{OH} = –8 mA	2.3 V	2.3 V				1.7			1.7			
		I _{OH} = –10 mA	3 V	3 V				2.2			2.2			
		I _{OH} = –12 mA	4.5 V	4.5 V				3.7			3.7			
V _{OL}	Low-level output voltage ⁽⁴⁾	I _{OL} = 0.1 mA	1.1V – 5.5V	1.1V – 5.5V				0.1			0.1			V
		I _{OL} = 0.5 mA	1.1 V	1.1 V				0.27			0.27			
		I _{OL} = 3 mA	1.4 V	1.4 V				0.35			0.35			
		I _{OL} = 4.5 mA	1.65 V	1.65 V				0.45			0.45			
		I _{OL} = 8 mA	2.3 V	2.3 V				0.7			0.7			
		I _{OL} = 10 mA	3 V	3 V				0.8			0.8			
		I _{OL} = 8 mA	4.5 V	4.5 V				0.55			0.55			
		I _{OL} = 12 mA	4.5 V	4.5 V				0.8			0.8			
I _I	Input leakage current	OE V _I = V _{CC} or GND	1.1V – 5.5V	1.1V – 5.5V	–0.1	1.5	–0.1	1.5	–0.1	2	μA			
		Data Inputs (Ax, Bx) V _I = V _{CCI} or GND	1.1V – 5.5V	1.1V – 5.5V	–0.1	1.5	–0.1	1.5	–2	2	μA			
I _{off}	Partial power down current	A Port or B Port V _I or V _O = 0 V - 5.5 V	0 V	0 V - 5.5 V	–1.5	1.5	–2	2	–2.5	2.5	μA			
			0 V - 5.5 V	0 V	–1.5	1.5	–2	2	–2.5	2.5				
I _{off-float}	Floating supply Partial power down current	A Port or B Port V _I or V _O = GND	Floating ⁽⁵⁾	0 V - 5.5 V	–1.5	1.5	–2	2	–2.5	2.5	μA			
			0 V - 5.5 V	Floating ⁽⁵⁾	–1.5	1.5	–2	2	–2.5	2.5				
I _{OZ}	Tri-state output current	A or B Port: V _I = V _{CCI} or GND V _O = V _{CCO} or GND OE = GND	1.1V – 5.5V	1.1V – 5.5V	–0.3	0.3	–1	1	–2	2	μA			
I _{CCA}	V _{CCA} supply current	V _I = V _{CCI} or GND I _O = 0	1.1V – 5.5V	1.1V – 5.5V	1.5			2.5			6	μA		
			0 V	5.5 V	–0.3			–1						
			5.5 V	0 V	1			1.5			3			
		V _I = GND I _O = 0	5.5 V	Floating ⁽⁵⁾	1.5			7			15			
I _{CCB}	V _{CCB} supply current	V _I = V _{CCI} or GND I _O = 0	1.1V – 5.5V	1.1V – 5.5V	1.5			2.5			6	μA		
			0 V	5.5 V	1			1.5			3			
			5.5 V	0 V	–0.3			–1			–1			
		V _I = GND I _O = 0	Floating ⁽⁵⁾	5.5 V	1.5			7			15			
I _{CCA} + I _{CCB}	Combined supply current	V _I = V _{CCI} or GND I _O = 0	1.1V – 5.5V	1.1V – 5.5V	2.5			3			6	μA		
C _i	Control Input Capacitance	V _I = 3.3 V or GND	3.3 V	3.3 V	2.75			3			3.5	pF		

7.5 Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)^{(1) (2)}

PARAMETER		TEST CONDITIONS	V _{CCA}	V _{CCB}	Operating free-air temperature (T _A)									UNIT
					25°C			−40°C to 85°C			−40°C to 125°C			
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
C _{io}	Data I/O Capacitance	OE = GND, V _O = 1.65V DC +1 MHz -16 dBm sine wave	3.3 V	3.3 V	3			4			4			pF

- (1) V_{CCI} is the V_{CC} associated with the input port
- (2) V_{CCO} is the V_{CC} associated with the output port
- (3) Tested at V_I = V_{T+(MAX)}
- (4) Tested at V_I = V_{T-(MIN)}
- (5) Floating is defined as a node that is both not actively driven by an external device and has leakage not exceeding 10nA

7.6 Switching Characteristics, $V_{CCA} = 1.2 \pm 0.1 \text{ V}$

See 图 8-1 and 表 8-1 for test circuit and loading. See 图 8-2, 图 8-3, and 图 8-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V _{CCB})												UNIT						
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V				3.3 ± 0.3 V			5.0 ± 0.5 V		
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX		MIN	TYP	MAX	MIN	TYP	MAX
t _{pd}	Propagation delay	A	B	-40°C to 85°C	3.3		96	0.5		43	0.5		37	0.5		32	0.5		30	0.5		31	ns
				-40°C to 125°C	5.7		60	3.0		39	1.4		33	0.5		28	0.5		27	0.5		26	
		B	A	-40°C to 85°C	3.3		95	1.9		80	0.5		75	0.5		70	0.5		69	0.5		69	
				-40°C to 125°C	5.7		60	4.1		51	2.9		48	1.8		45	1.5		44	1.3		44	
t _{dis}	Disable time	OE	A	-40°C to 85°C	28.8		133	28.5		130	28.4		133	28.8		137	28.4		143	18.7		211	ns
				-40°C to 125°C	43.3		133	43.3		130	43.7		130	44.7		131	45.4		134	31.8		140	
		OE	B	-40°C to 85°C	32.5		150	27.6		117	25.8		110	22.5		104	22.1		112	20.1		181	
				-40°C to 125°C	48.3		149	43.2		120	40.8		113	36.8		104	36.5		107	33.8		111	
t _{en}	Enable time	OE	A	-40°C to 85°C	24.1		237	22.1		229	21.4		230	21.3		232	21.7		235	22.7		244	ns
				-40°C to 125°C	34.9		156	33.3		167	32.0		169	31.7		173	32.0		177	34.2		187	
		OE	B	-40°C to 85°C	21.3		237	14.3		152	11.2		140	8.8		130	8.2		130	8.4		132	
				-40°C to 125°C	29.8		143	23.0		116	18.6		107	15.4		97	14.5		97	14.8		103	

7.7 Switching Characteristics, $V_{CCA} = 1.5 \pm 0.1 \text{ V}$

See 图 8-1 and 表 8-1 for test circuit and loading. See 图 8-2, 图 8-3, and 图 8-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V _{CCB})															UNIT			
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V				5.0 ± 0.5 V		
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX		MIN	TYP	MAX
t _{pd}	Propagation delay	A	B	-40°C to 85°C	1.9		80	0.5		31	0.5		25	0.5		19	0.5		17	0.5		15	ns
				-40°C to 125°C	4.1		51	1.6		31	0.5		25	0.5		20	0.5		18	0.5		16	
		B	A	-40°C to 85°C	0.5		43	0.5		31	0.5		28	0.5		26	0.5		25	0.5		24	
				-40°C to 125°C	3.0		39	1.6		31	0.5		28	0.5		26	0.5		25	0.5		24	
t _{dis}	Disable time	OE	A	-40°C to 85°C	20.0		91	19.0		82	18.8		81	19.2		82	19.6		83	12.2		87	ns
				-40°C to 125°C	34.9		95	32.6		86	32.8		85	33.4		87	34.2		88	24.6		92	
		OE	B	-40°C to 85°C	27.4		127	21.7		91	19.9		82	16.3		71	15.9		71	13.7		70	
				-40°C to 125°C	44.4		130	36.7		95	34.7		86	30.2		75	29.8		75	26.6		74	
t _{en}	Enable time	OE	A	-40°C to 85°C	14.9		102	14.4		86	13.5		88	12.7		90	12.6		92	13.2		97	ns
				-40°C to 125°C	25.5		102	25.2		89	24.1		91	22.8		93	22.8		96	23.5		100	
		OE	B	-40°C to 85°C	17.9		175	12.7		80	9.1		69	6.1		57	4.9		53	4.5		54	
				-40°C to 125°C	26.6		135	21.0		81	16.8		71	12.5		60	10.8		56	10.4		57	

7.8 Switching Characteristics, $V_{CCA} = 1.8 \pm 0.15 \text{ V}$

See 图 8-1 and 表 8-1 for test circuit and loading. See 图 8-2, 图 8-3, and 图 8-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V _{CCB})												UNIT						
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V				3.3 ± 0.3 V			5.0 ± 0.5 V		
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX		MIN	TYP	MAX	MIN	TYP	MAX
t _{pd}	Propagation delay	A	B	-40°C to 85°C	0.5		75	0.5		28	0.5		22	0.5		17	0.5		14	0.5		12	ns
				-40°C to 125°C	2.9		48	0.5		28	0.5		23	0.5		17	0.5		15	0.5		13	
		B	A	-40°C to 85°C	0.5		37	0.5		25	0.5		22	0.5		19	0.5		19	0.5		18	
				-40°C to 125°C	1.4		33	0.5		25	0.5		23	0.5		20	0.5		19	0.5		19	
t _{dis}	Disable time	OE	A	-40°C to 85°C	17.2		79	14.7		67	14.5		65	14.3		65	14.4		66	8.5		68	ns
				-40°C to 125°C	30.9		83	28.0		71	26.6		69	27.5		70	27.2		71	20.0		73	
		OE	B	-40°C to 85°C	25.4		121	18.7		81	16.5		71	12.8		60	12.5		58	9.8		55	
				-40°C to 125°C	41.7		123	34.0		86	30.3		76	26.2		64	25.3		62	21.8		59	
t _{en}	Enable time	OE	A	-40°C to 85°C	10.9		88	9.5		66	9.4		63	8.6		65	8.2		66	8.1		69	ns
				-40°C to 125°C	20.3		87	19.0		69	18.9		67	17.6		68	17.1		70	17.1		73	
		OE	B	-40°C to 85°C	16.7		177	10.4		75	8.1		58	4.9		46	3.3		42	2.2		39	
				-40°C to 125°C	25.1		135	18.7		77	15.5		60	11.0		49	8.7		44	7.3		42	

7.9 Switching Characteristics, $V_{CCA} = 2.5 \pm 0.2 \text{ V}$

See 图 8-1 and 表 8-1 for test circuit and loading. See 图 8-2, 图 8-3, and 图 8-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V _{CCB})															UNIT			
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V			3.3 ± 0.3 V				5.0 ± 0.5 V		
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX		MIN	TYP	MAX
t _{pd}	Propagation delay	A	B	-40°C to 85°C	0.5		70	0.5		26	0.5		20	0.5		14	0.5		12	0.5		9	ns
				-40°C to 125°C	1.8		45	0.5		26	0.5		20	0.5		14	0.5		12	0.5		10	
		B	A	-40°C to 85°C	0.5		32	0.5		19	0.5		17	0.5		14	0.5		13	0.5		13	
				-40°C to 125°C	0.5		28	0.5		20	0.5		17	0.5		14	0.5		13	0.5		13	
t _{dis}	Disable time	OE	A	-40°C to 85°C	12.9		65	10.5		51	9.0		51	8.1		43	8.4		44	5.0		45	ns
				-40°C to 125°C	24.9		68	21.8		55	19.7		50	18.2		47	18.6		48	15.0		49	
		OE	B	-40°C to 85°C	23.2		112	16.5		74	14.0		61	9.0		46	9.1		44	6.4		39	
				-40°C to 125°C	38.7		115	30.9		79	27.1		66	21.6		51	20.5		48	16.8		43	
t _{en}	Enable time	OE	A	-40°C to 85°C	7.9		80	5.9		50	5.1		44	4.7		39	4.4		40	3.7		41	ns
				-40°C to 125°C	15.6		74	13.5		53	12.4		47	12.0		42	11.5		43	10.8		44	
		OE	B	-40°C to 85°C	16.3		183	9.2		74	6.0		54	4.0		36	2.1		31	0.5		27	
				-40°C to 125°C	24.4		139	17.2		76	13.0		57	9.8		38	7.1		33	4.7		29	

7.10 Switching Characteristics, $V_{CCA} = 3.3 \pm 0.3 \text{ V}$

See 图 8-1 and 表 8-1 for test circuit and loading. See 图 8-2, 图 8-3, and 图 8-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V _{CCB})												UNIT						
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V				3.3 ± 0.3 V			5.0 ± 0.5 V		
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX		MIN	TYP	MAX	MIN	TYP	MAX
t _{pd}	Propagation delay	A	B	-40°C to 85°C	0.5		69	0.5		25	0.5		19	0.5		13	0.5		11	0.5		8	ns
				-40°C to 125°C	1.5		44	0.5		25	0.5		19	0.5		13	0.5		11	0.5		9	
		B	A	-40°C to 85°C	0.5		30	0.5		17	0.5		14	0.5		12	0.5		11	0.5		10	
				-40°C to 125°C	0.5		27	0.5		18	0.5		15	0.5		12	0.5		11	0.5		10	
t _{dis}	Disable time	OE	A	-40°C to 85°C	12.9		62	10.1		47	8.7		42	6.9		39	6.6		39	6.9		40	ns
				-40°C to 125°C	24.0		65	20.6		51	18.4		46	15.7		40	15.3		39	15.9		40	
		OE	B	-40°C to 85°C	22.7		109	15.7		71	13.2		59	8.5		42	7.6		38	4.7		34	
				-40°C to 125°C	37.6		111	29.5		75	25.4		63	19.2		46	18.5		42	14.2		36	
t _{en}	Enable time	OE	A	-40°C to 85°C	6.6		85	4.2		45	3.0		37	2.4		31	2.2		30	1.7		30	ns
				-40°C to 125°C	13.6		72	10.9		47	9.3		40	8.2		33	8.1		32	7.5		33	
		OE	B	-40°C to 85°C	16.3		192	8.9		76	5.4		55	2.6		34	1.8		27	0.5		22	
				-40°C to 125°C	24.3		144	16.7		78	12.2		57	8.0		36	6.6		29	3.7		24	

7.11 Switching Characteristics, $V_{CCA} = 5.0 \pm 0.5 \text{ V}$

See 图 8-1 and 表 8-1 for test circuit and loading. See 图 8-2, 图 8-3, and 图 8-4 for measurement waveforms.

PARAMETER		FROM	TO	Test Conditions	B-Port Supply Voltage (V _{CCB})												UNIT						
					1.2 ± 0.1 V			1.5 ± 0.1 V			1.8 ± 0.15 V			2.5 ± 0.2 V				3.3 ± 0.3 V			5.0 ± 0.5 V		
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX		MIN	TYP	MAX	MIN	TYP	MAX
t _{pd}	Propagation delay	A	B	-40°C to 85°C	0.5		69	0.5		24	0.5		18	0.5		13	0.5		10	0.5		8	ns
				-40°C to 125°C	1.3		44	0.5		24	0.5		19	0.5		13	0.5		11	0.5		8	
		B	A	-40°C to 85°C	0.5		31	0.5		15	0.5		12	0.5		9	0.5		8	0.5		8	
				-40°C to 125°C	0.5		26	0.5		16	0.5		13	0.5		10	0.5		9	0.5		8	
t _{dis}	Disable time	OE	A	-40°C to 85°C	10.8		60	7.7		42	5.9		36	4.2		31	3.4		30	2.8		26	ns
				-40°C to 125°C	20.8		62	17.0		46	14.5		40	11.8		33	10.4		31	9.6		29	
		OE	B	-40°C to 85°C	9.7		109	5.9		69	13.2		56	8.4		40	6.9		36	3.7		30	
				-40°C to 125°C	37.4		111	29.2		73	24.6		60	18.1		43	16.4		39	12.2		33	
t _{en}	Enable time	OE	A	-40°C to 85°C	6.0		102	2.8		44	1.2		33	0.5		25	0.5		22	0.5		21	ns
				-40°C to 125°C	12.4		81	8.8		46	6.5		36	4.7		27	4.2		24	4.4		23	
		OE	B	-40°C to 85°C	16.7		212	8.8		82	4.8		58	1.6		35	0.5		26	0.5		19	
				-40°C to 125°C	24.8		158	16.7		83	11.7		60	6.9		37	4.7		28	3.5		21	

7.12 Operating Characteristics

$T_A = 25^\circ\text{C}$ ⁽¹⁾

PARAMETER		Test Conditions	Supply Voltage ($V_{CCB} = V_{CCA}$)						UNIT
			1.2 ± 0.1V	1.5 ± 0.1V	1.8 ± 0.15V	2.5 ± 0.2V	3.3 ± 0.3V	5.0 ± 0.5V	
			TYP	TYP	TYP	TYP	TYP	TYP	
C_{pdA} ⁽²⁾	A to B: outputs enabled	A Port CL = 0, RL = Open f = 10 MHz t _{rise} = t _{fall} = 1 ns	2	2	2	2	2	3	pF
	A to B: outputs disabled		2	2	2	2	2	3	
	B to A: outputs enabled		12	12	12	13	13	16	
	B to A: outputs disabled		2	2	2	2	2	3	
C_{pdB} ⁽³⁾	A to B: outputs enabled	B Port CL = 0, RL = Open f = 10 MHz t _{rise} = t _{fall} = 1 ns	12	12	12	13	13	16	pF
	A to B: outputs disabled		2	2	2	2	2	3	
	B to A: outputs enabled		2	2	2	2	2	3	
	B to A: outputs disabled		2	2	2	2	2	3	

- (1) See the [CMOS Power Consumption and \$C_{pd}\$ Calculation](#) application report for additional information about how power dissipation capacitance affects power consumption.
- (2) A-Port power dissipation capacitance per transceiver.
- (3) B-Port power dissipation capacitance per transceiver.

7.13 Typical Characteristics

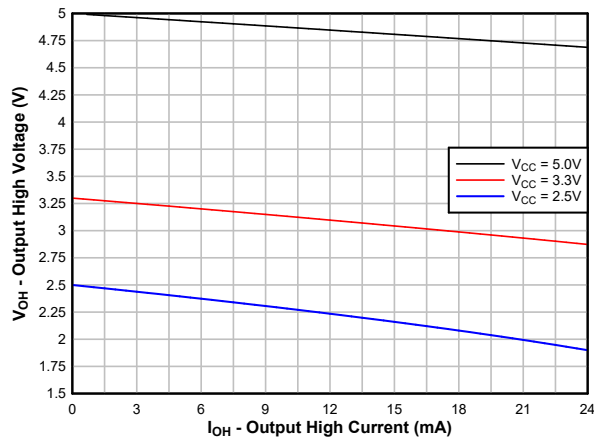


图 7-1. Typical ($T_A=25^\circ\text{C}$) Output High Voltage (V_{OH}) vs Source Current (I_{OH})

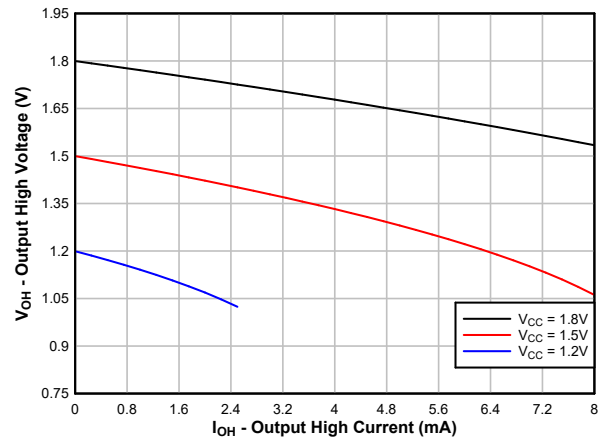


图 7-2. Typical ($T_A=25^\circ\text{C}$) Output High Voltage (V_{OH}) vs Source Current (I_{OH})

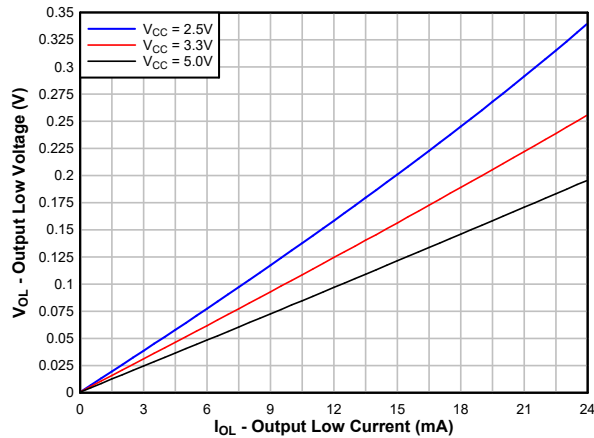


图 7-3. Typical ($T_A=25^\circ\text{C}$) Output Low Voltage (V_{OL}) vs Sink Current (I_{OL})

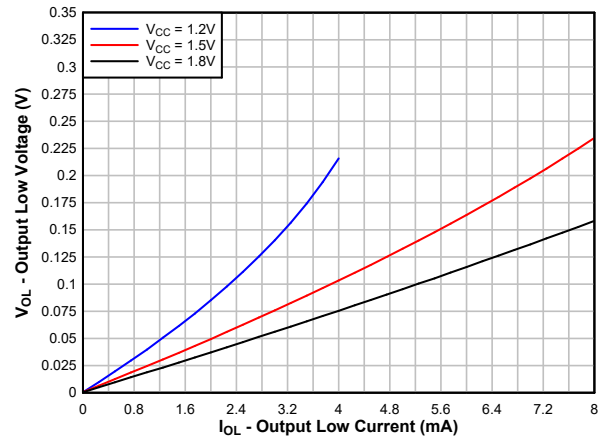


图 7-4. Typical ($T_A=25^\circ\text{C}$) Output Low Voltage (V_{OL}) vs Sink Current (I_{OL})

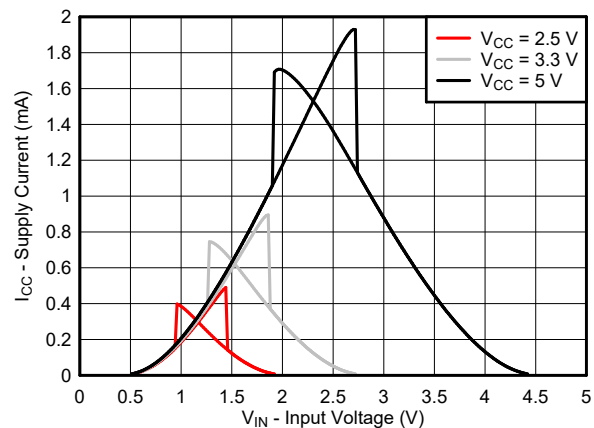


图 7-5. Typical ($T_A=25^\circ\text{C}$) Supply Current (I_{CC}) vs Input Voltage (V_{IN})

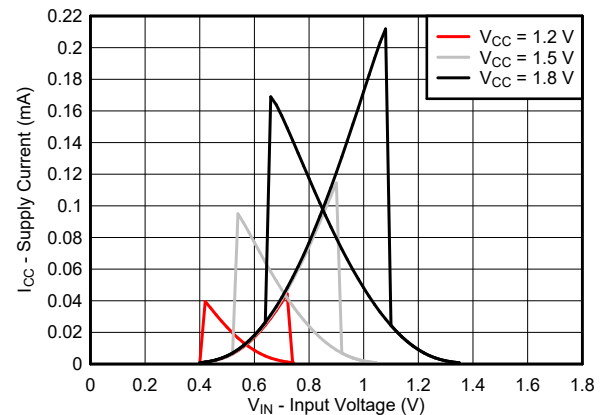


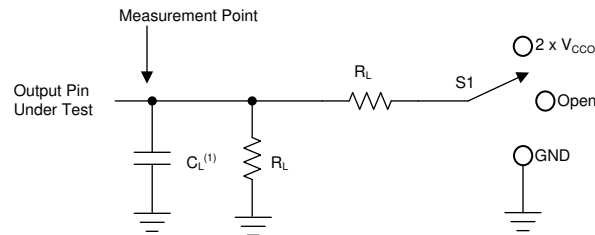
图 7-6. Typical ($T_A=25^\circ\text{C}$) Supply Current (I_{CC}) vs Input Voltage (V_{IN})

8 Parameter Measurement Information

8.1 Load Circuit and Voltage Waveforms

Unless otherwise noted, generators supply all input pulses that have the following characteristics:

- $f = 1 \text{ MHz}$
- $Z_O = 50 \Omega$
- $\Delta t/\Delta V \leq 1 \text{ ns/V}$

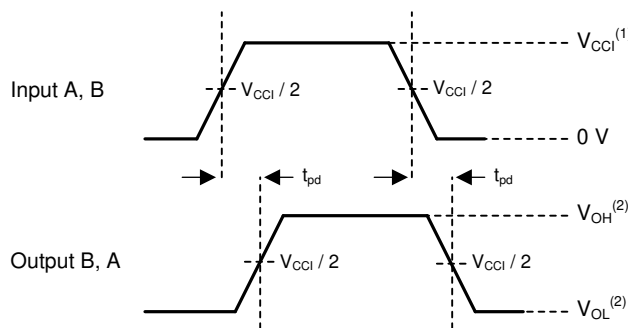


A. C_L includes probe and jig capacitance.

图 8-1. Load Circuit

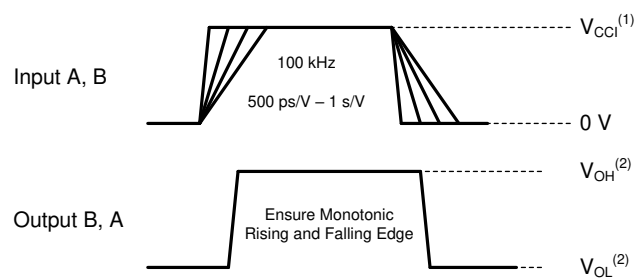
表 8-1. Load Circuit Conditions

Parameter	V_{CCO}	R_L	C_L	S_1	V_{TP}
t_{pd} Propagation (delay) time	1.1 V – 5.5 V	10 k Ω	5 pF	Open	N/A
t_{en}, t_{dis} Enable time, disable time	1.1 V – 1.6 V	10 k Ω	5 pF	$2 \times V_{CCO}$	0.1 V
	1.65 V – 2.7 V	10 k Ω	5 pF	$2 \times V_{CCO}$	0.15 V
	3.0 V – 5.5 V	10 k Ω	5 pF	$2 \times V_{CCO}$	0.3 V
t_{en}, t_{dis} Enable time, disable time	1.1 V – 1.6 V	10 k Ω	5 pF	GND	0.1 V
	1.65 V – 2.7 V	10 k Ω	5 pF	GND	0.15 V
	3.0 V – 5.5 V	10 k Ω	5 pF	GND	0.3 V



1. V_{CCI} is the supply pin associated with the input port.
2. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L , C_L , and S_1

图 8-2. Propagation Delay



1. V_{CCI} is the supply pin associated with the input port.
2. V_{OH} and V_{OL} are typical output voltage levels that occur with specified R_L , C_L , and S_1

图 8-3. Input Transition Rise and Fall Rate



1. Output waveform on the condition that input is driven to a valid Logic Low.
2. Output waveform on the condition that input is driven to a valid Logic High.
3. V_{CCO} is the supply pin associated with the output port.
4. V_{OH} and V_{OL} are typical output voltage levels with specified R_L , C_L , and S_1 .

图 8-4. Enable Time And Disable Time

9 Detailed Description

9.1 Overview

The TXU0202 is a 4-bit translating transceiver that uses two individually configurable power-supply rails. The device is operational with V_{CCA} and V_{CCB} supplies as low as 1.1 V and as high as 5.5 V. Additionally, the device can be operated with $V_{CCA} = V_{CCB}$. The A port is designed to track V_{CCA} , and the B port is designed to track V_{CCB} .

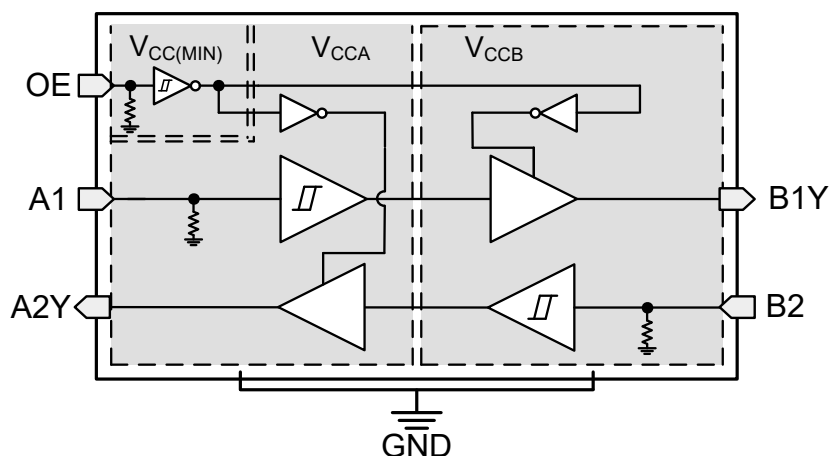
The TXU0202 device is designed for asynchronous communication between data buses, and transmits data with fixed direction from the A bus to the B bus on some channels and from the B bus to the A bus on the remaining channels. The output-enable input (OE) is used to disable the outputs so the buses are effectively isolated. The output-enable pin of the TXU0202 (OE) can be referenced to either V_{CCA} or V_{CCB} . The OE pin can be left floating or externally pulled down to ground to ensure the high-impedance state of the level shifter outputs during power up or power down.

This device is fully specified for partial-power-down applications using the I_{off} current. The I_{off} protection circuitry ensures that no excessive current is drawn from or sourced into an input or output while the device is powered down.

The VCC isolation or VCC disconnect feature ensures that if either VCC is less than 100 mV or disconnected with the complementary supply within recommended operating conditions, outputs are disabled and set to the high-impedance state while the supply current is maintained. The I_{off_float} circuitry ensures that no excessive current is drawn from or sourced into an input or output while the supply is floating.

Glitch-free power supply sequencing allows either supply rail to be powered on or off in any order while providing robust power sequencing performance.

9.2 Functional Block Diagram



9.3 Feature Description

9.3.1 CMOS Schmitt-Trigger Inputs with Integrated Pulldowns

Standard CMOS inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the [Electrical Characteristics](#). The worst case resistance is calculated with the maximum input voltage, given in the [Absolute Maximum Ratings](#), and the maximum input leakage current, given in the [Electrical Characteristics](#), using ohm's law ($R = V \div I$).

The Schmitt-trigger input architecture provides hysteresis as defined by ΔV_T in the [Electrical Characteristics](#), which makes this device extremely tolerant to slow or noisy inputs. Driving the inputs slowly will increase dynamic current consumption of the device. See [Understanding Schmitt Triggers](#) for additional information regarding Schmitt-trigger inputs.

9.3.1.1 Inputs with Integrated Static Pull-Down Resistors

This device has 5 M Ω typical integrated weak pull-downs for each input. This feature allows all inputs to be left floating without the concern for unstable outputs or increased current consumption. This also helps to reduce external component count for applications where not all channels are used or need to be fixed low. If an external pull-up is required, it should be no larger than 1 M Ω to avoid contention with the 5 M Ω internal pull-down.

9.3.2 Control Logic (OE) with $V_{CC(MIN)}$ Circuitry

The output-enable input (OE) is used to disable the outputs so the buses are effectively isolated. The output-enable pin of the TXU0x04 has $V_{CC(MIN)}$ circuitry, which allows the OE pin to operate with the lower supply voltage. The [Over-Voltage Tolerant Inputs](#) feature allows the OE pin to operate with the higher supply voltage. This combination means that the enable pin can be referenced to either V_{CCA} or V_{CCB} supply. Multiple permutations of each device are possible since the controller can be placed on either the A or B port and can still control the enable pin.

9.3.3 Balanced High-Drive CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The high drive capability of this device creates fast edges into light loads, so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. [Absolute Maximum Ratings](#) defines the electrical and thermal limits that must be followed at all times.

9.3.4 VCC Isolation and V_{CC} Disconnect

The outputs for this device are disabled and enter a high-impedance state when either supply is <100 mV or left floating (disconnected), with the complementary supply within recommended operating conditions. It is recommended that the inputs are kept low before floating (disconnecting) either supply.

The $I_{CCX(floating)}$ in the [Electrical Characteristics](#) specifies the maximum supply current. The $I_{off(float)}$ in the [Electrical Characteristics](#) specifies the maximum leakage into or out of any input or output pin on the device.

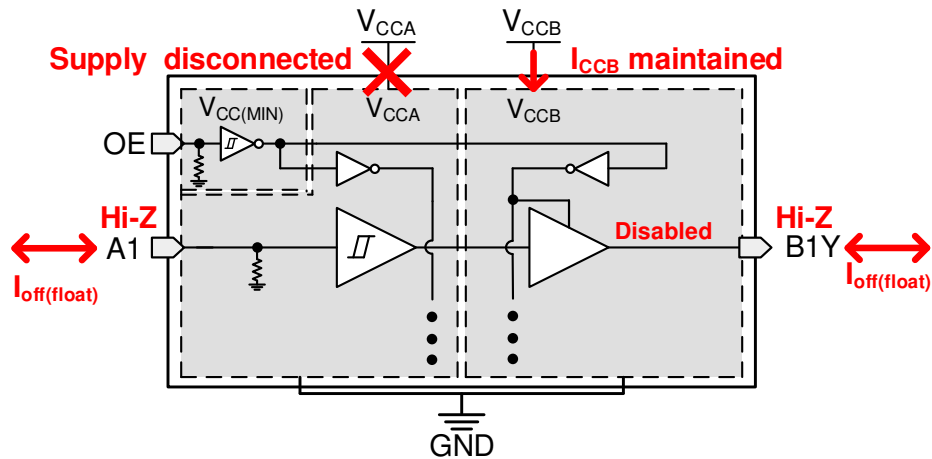


图 9-1. V_{CC} Disconnect Feature

9.3.5 Over-Voltage Tolerant Inputs

Input signals to this device can be driven above the supply voltage so long as they remain below the maximum input voltage value specified in the [Recommended Operating Conditions](#).

9.3.6 Glitch-Free Power Supply Sequencing

Either supply rail may be powered on or off in any order without producing a glitch on the inputs or outputs (that is, where the output erroneously transitions to V_{CC} when it should be held low or vice versa). Glitches of this nature can be misinterpreted by a peripheral as a valid data bit, which could trigger a false device reset of the peripheral, a false device configuration of the peripheral, or even a false data initialization by the peripheral.

9.3.7 Negative Clamping Diodes

图 9-2 depicts the inputs and outputs to this device that have negative clamping diodes.

CAUTION

Voltages beyond the values specified in the [Absolute Maximum Ratings](#) table can cause damage to the device. The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

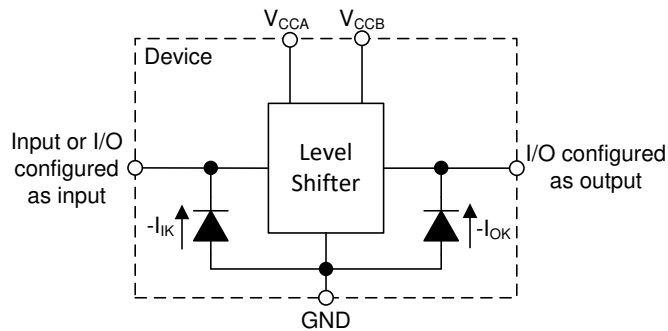


图 9-2. Electrical Placement of Clamping Diodes for Each Input and Output

9.3.8 Fully Configurable Dual-Rail Design

The V_{CCA} and V_{CCB} pins can be supplied at any voltage from 1.1 V to 5.5 V, making the device suitable for translating between any of the voltage nodes (1.2 V, 1.5 V, 1.8 V, 3.3 V, and 5.0 V).

9.3.9 Supports High-Speed Translation

The TXU0202 device can support high data-rate applications. The translated signal data rate can be up to 200 Mbps when the signal is translated from 3.3 V to 5.0 V.

9.4 Device Functional Modes

表 9-1. Function Table

CONTROL INPUTS	Port Status		OPERATION
	Input	Output	
H	L	L	Unidirectional non-inverting voltage translation
H	H	H	Unidirectional non-inverting voltage translation
L	X	Hi-Z	Isolation

10 Application and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

10.1 Application Information

The TXU0202 device can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another. The TXU0202 device is ideal for use in applications where a push-pull driver is connected to the data Inputs. The maximum data rate can be up to 200 Mbps when device translates a signal from 3.3 V to 5.0 V.

10.2 Typical Application

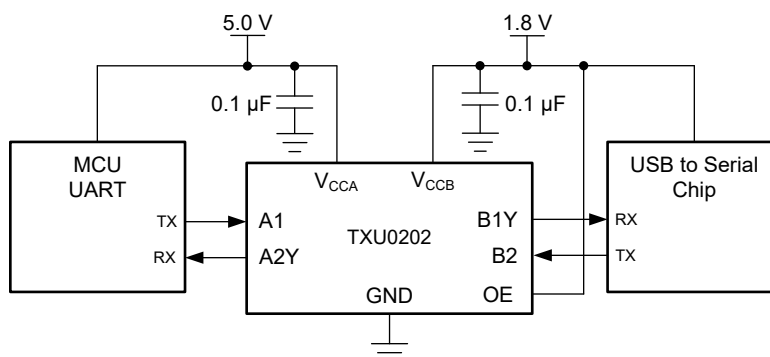


图 10-1. TXU0202 UART Application

10.2.1 Design Requirements

Use the parameters listed in 表 10-1 for this design example.

表 10-1. Design Parameters

DESIGN PARAMETERS	EXAMPLE VALUES
Input voltage range	1.1 V to 5.5 V
Output voltage range	1.1 V to 5.5 V

10.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
 - Use the supply voltage of the device that is driving the TXU0202 device to determine the input voltage range. For a valid logic-high, the value must exceed the positive-going input-threshold voltage (V_{T+}) of the input port. For a valid logic low the value must be less than the negative-going input-threshold voltage (V_{T-}) of the input port.
- Output voltage range
 - Use the supply voltage of the device that the TXU0202 device is driving to determine the output voltage range.

10.2.3 Application Curve

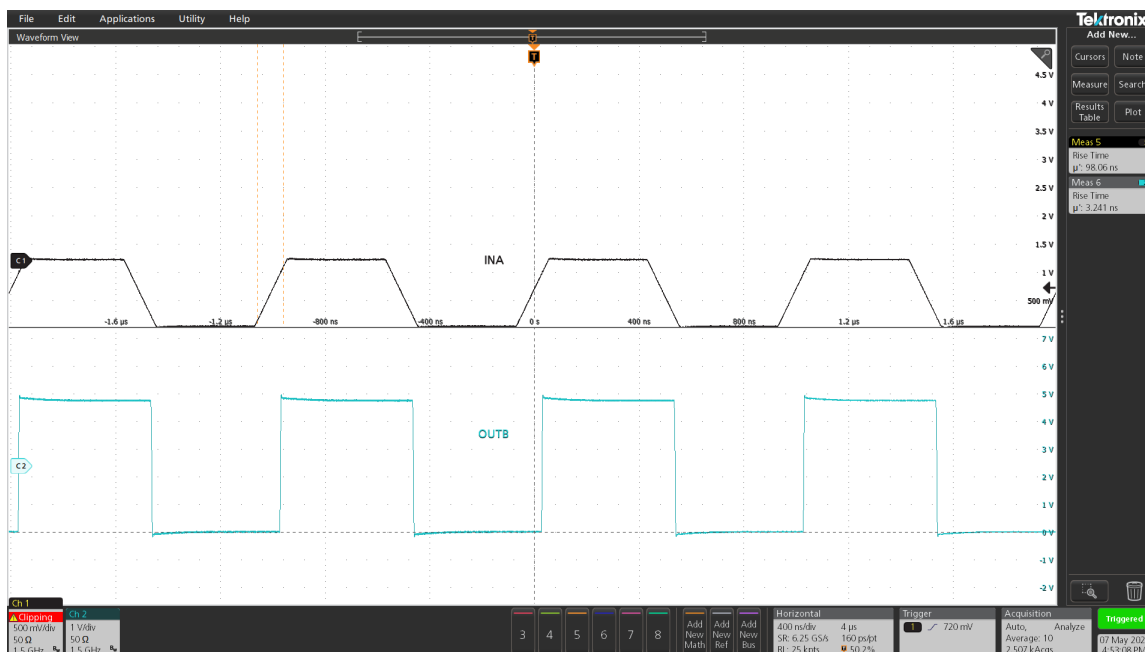


图 10-2. Up Translation at 1 MHz (1.2 V to 5 V)

11 Power Supply Recommendations

Always apply a ground reference to the GND pins first. This device is designed for glitch free power sequencing without any supply sequencing requirements such as ramp order or ramp rate.

[Glitch-Free Power Supply Sequencing](#) describes how this device was designed with various power supply sequencing methods in mind to help prevent unintended triggering of downstream devices.

12 Layout

12.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines are recommended:

- Use bypass capacitors on the power supply pins and place them as close to the device as possible. A 0.1 μF capacitor is recommended, but transient performance can be improved by having 1 μF and 0.1 μF capacitors in parallel as bypass capacitors.
- The high drive capability of this device creates fast edges into light loads so routing and load conditions should be considered to prevent ringing.

12.2 Layout Example

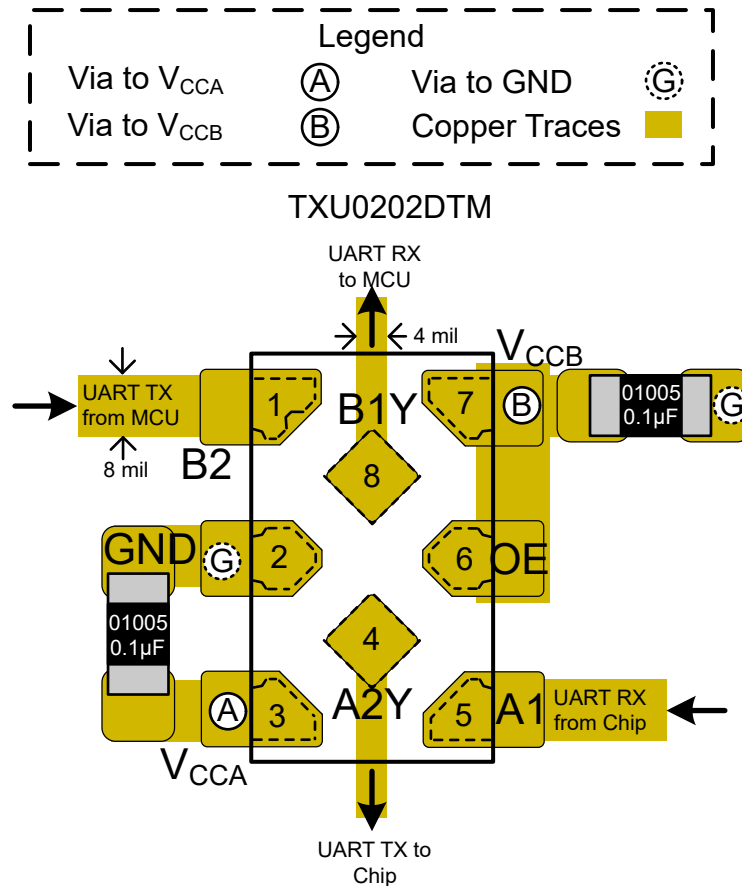


图 12-1. Layout Example – TXU0202

13 Device and Documentation Support

13.1 Device Support

13.1.1 Regulatory Requirements

No statutory or regulatory requirements apply to this device.

There are no special characteristics for this product.

13.2 Documentation Support

13.2.1 Related Documentation

- Texas Instruments, [Understanding Schmitt Triggers application report](#)
- Texas Instruments, [CMOS Power Consumption and \$C_{pd}\$ Calculation application report](#)

13.3 接收文档更新通知

要接收文档更新通知，请导航至 [ti.com](https://www.ti.com) 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

13.4 支持资源

[TI E2E™ 支持论坛](#) 是工程师的重要参考资料，可直接从专家获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题可获得所需的快速设计帮助。

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13.5 Trademarks

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13.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

13.7 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TXU0202DCUR	ACTIVE	VSSOP	DCU	8	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125		Samples
TXU0202DTMR	ACTIVE	X2SON	DTM	8	5000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	1LP	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

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⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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